SPICE Device Model SiA440DJ



Vishay Siliconix

N-Channel 40 V (D-S) MOSFET

DESCRIPTION

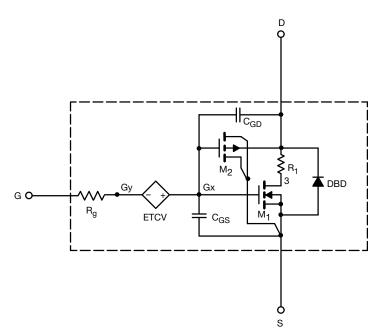
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},\ I_{D}=250\ \mu A$	1.1	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 9 \text{ A}$	0.021	0.021	Ω
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 7 \text{ A}$	0.022	0.022	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 10 \text{ V}, I_D = 9 \text{ A}$	51	45	S
Diode Forward Voltage	V _{SD}	I _S = 7 A	0.82	0.85	V
Dynamic ^b					
Input Capacitance	C _{iss}	V_{DS} = 20 V, V_{GS} = 0 V, f = 1 MHz	708	700	pF
Output Capacitance	C _{oss}		91	87	
Reverse Transfer Capacitance	C _{rss}		42	40	
Total Gate Charge	Qg	V_{DS} = 20 V, V_{GS} = 10 V, I_{D} = 9 A	13	14.3	nC
		$V_{DS} = 20 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 9 \text{ A}$	6.4	6.9	
Gate-Source Charge	Q _{gs}		1.4	1.4	
Gate-Drain Charge	Q _{gd}		2	2	

Notes

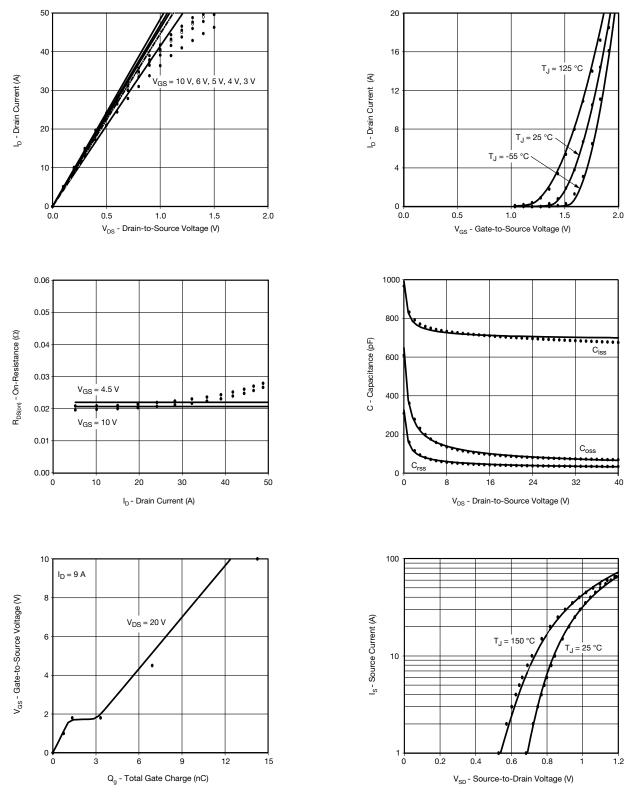
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.



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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data. Copyright: Vishay Intertechnology, Inc.

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